



STPS745D/F/G

POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	7.5 A
V_{RRM}	45 V
$T_j(max)$	175 °C
$V_F(max)$	0.57 V

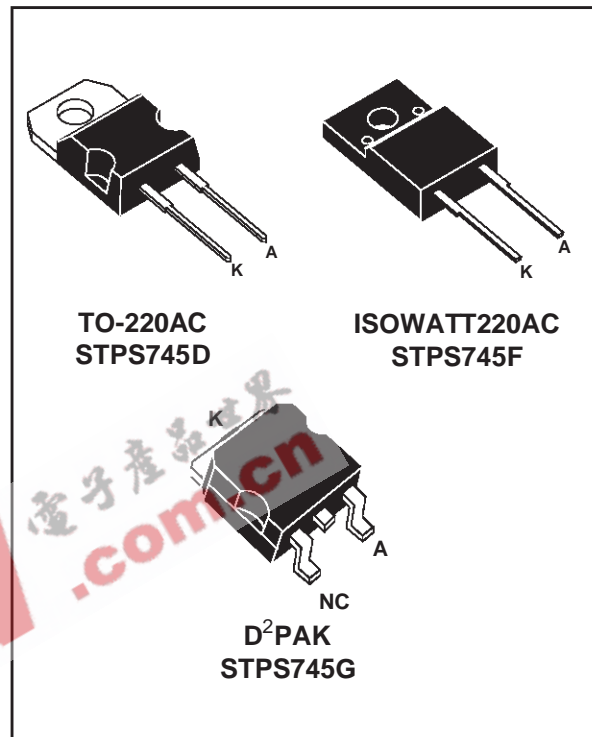
FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- INSULATED PACKAGE: ISOWATT220AC
Insulating voltage = 2000V DC
Capacitance = 12pF

DESCRIPTION

Single Schottky rectifier suited for Switch Mode Power Supply and high frequency DC to DC converters.

Packaged either in TO-220AC, ISOWATT220AC or D²PAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit	
V_{RRM}	Repetitive peak reverse voltage		45	V	
$I_{F(RMS)}$	RMS forward current		20	A	
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220AC/ D ² PAK	$T_c = 160^\circ\text{C}$	7.5	A
		ISOWATT220AC	$T_c = 145^\circ\text{C}$		
I_{FSM}	Surge non repetitive forward current	tp = 10 ms sinusoidal		150	A
I_{RRM}	Repetitive peak reverse current	tp = 2 μs square F = 1kHz		1	A
I_{RSM}	Non repetitive peak reverse current	tp = 100 μs square		2	A
T_{stg}	Storage temperature range		- 65 to + 175	°C	
T_j	Maximum operating junction temperature *		175	°C	
dV/dt	Critical rate of rise of reverse voltage		10000	V/ μs	

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AC / D ² PAK	3.0	°C/W
		ISOWATT220AC	5.5	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests Conditions		Min.	Typ.	Max.	Unit
I_R^*	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			100	μA
		$T_j = 125^\circ\text{C}$			5	15	mA
V_F^*	Forward voltage drop	$T_j = 125^\circ\text{C}$	$I_F = 7.5\text{ A}$		0.5	0.57	V
		$T_j = 25^\circ\text{C}$	$I_F = 15\text{ A}$			0.84	
		$T_j = 125^\circ\text{C}$	$I_F = 15\text{ A}$		0.65	0.72	

Pulse test : * $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation :

$$P = 0.42 \times I_{F(AV)} + 0.020 I_{F(RMS)}^2$$

Fig. 1: Average forward power dissipation versus average forward current.

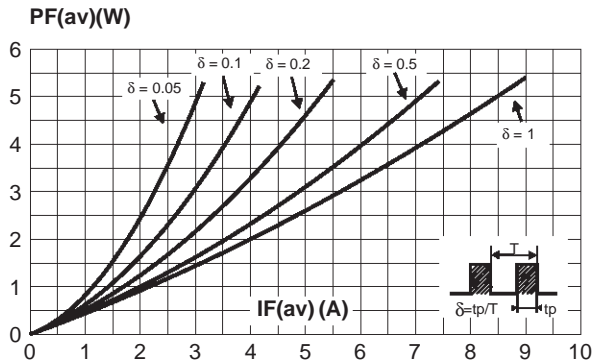


Fig. 2: Average current versus ambient temperature ($\delta = 0.5$).

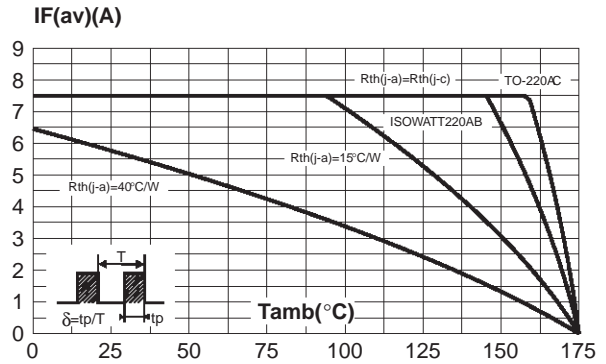


Fig. 3-1: Non repetitive surge peak forward current versus overload duration (maximum values) (TO-220AC and D²PAK).

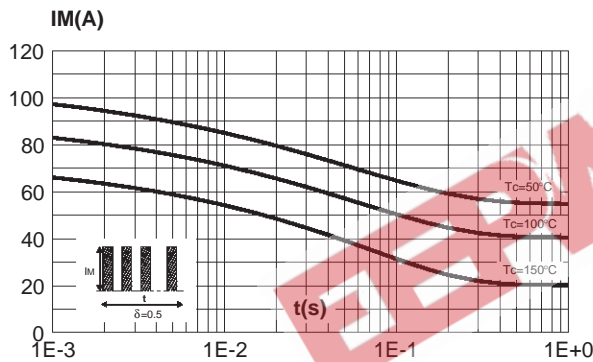


Fig. 3-2: Non repetitive surge peak forward current versus overload duration (maximum values) (ISOWATT220AC).

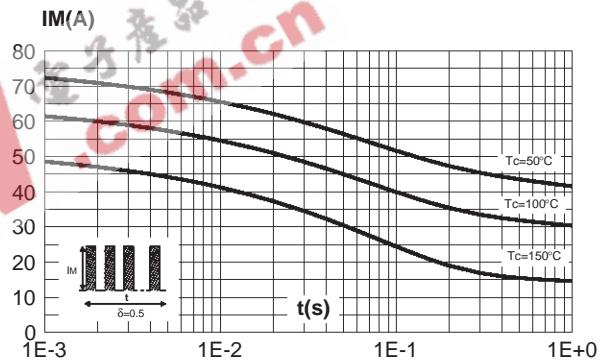


Fig. 4-1: Relative variation of thermal transient impedance junction to case versus pulse duration (TO-220AC and D²PAK).

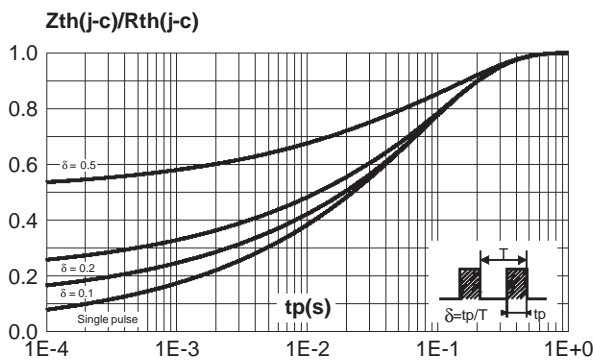


Fig. 4-2: Relative variation of thermal transient impedance junction to case versus pulse duration (ISOWATT220AC).

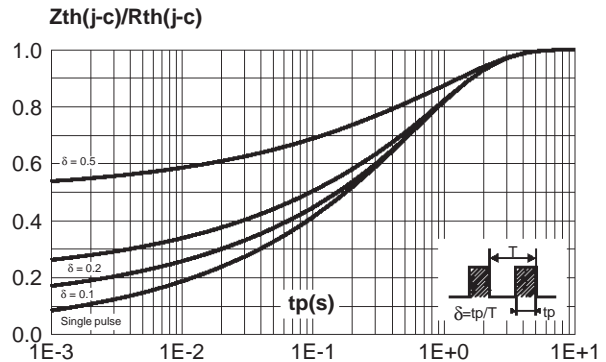


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values).

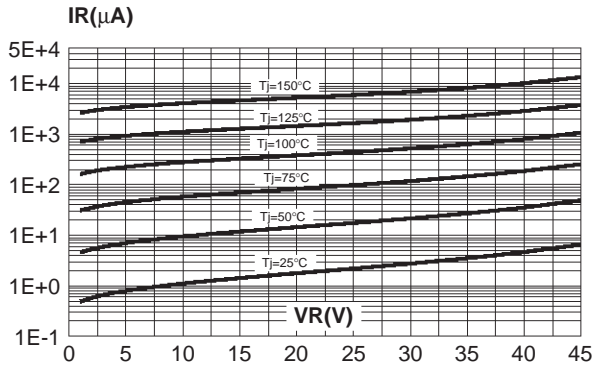


Fig. 6: Junction capacitance versus reverse voltage applied (typical values).

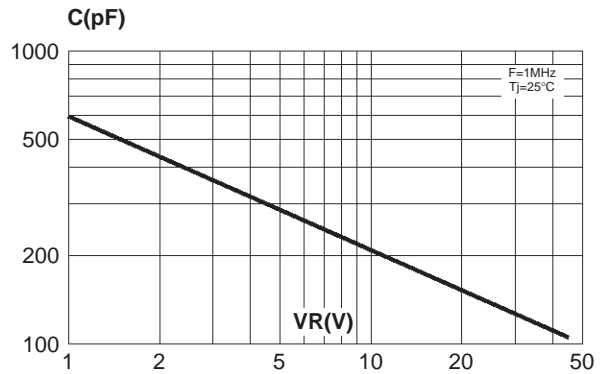


Fig. 7: Forward voltage drop versus forward current (maximum values).

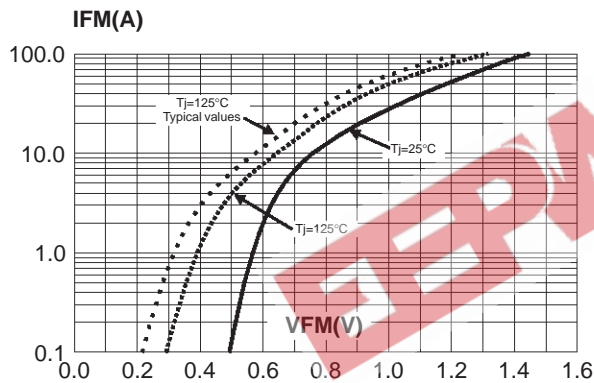
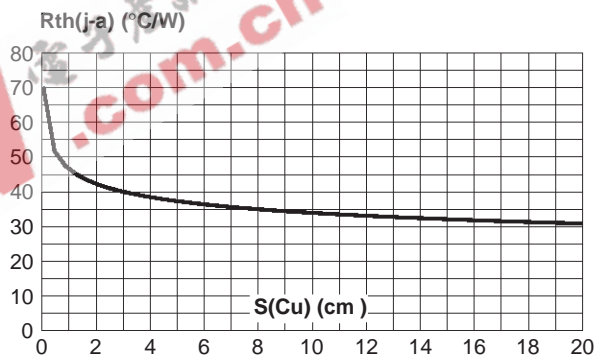
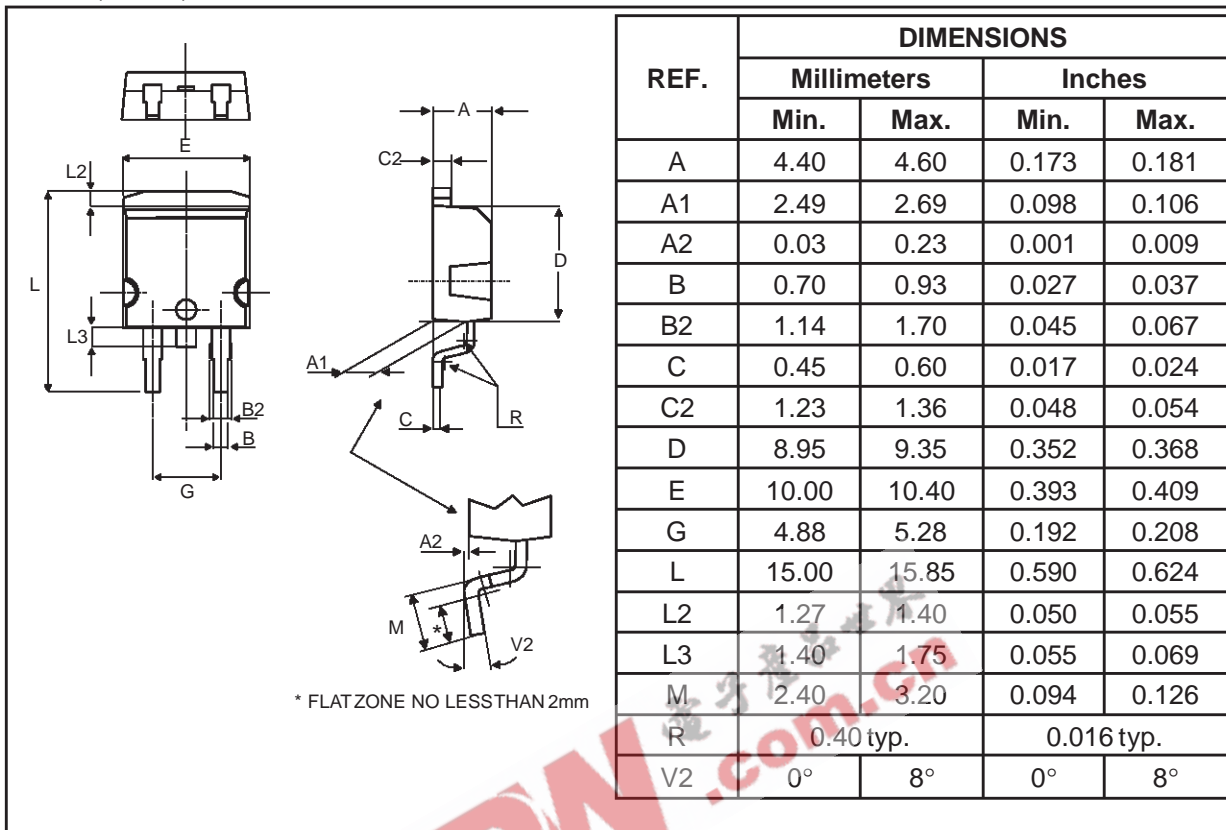


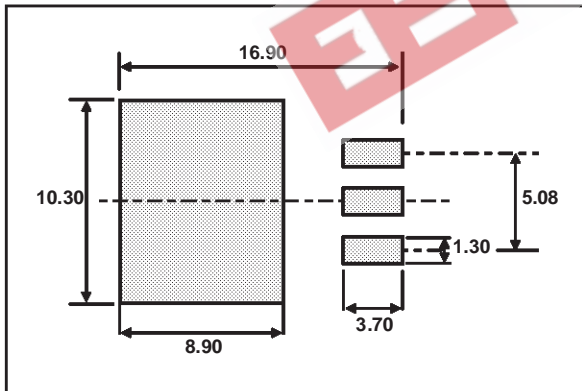
Fig. 8: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board, copper thickness: $35\mu\text{m}$).



PACKAGE MECHANICAL DATA
D²PAK (Plastic)

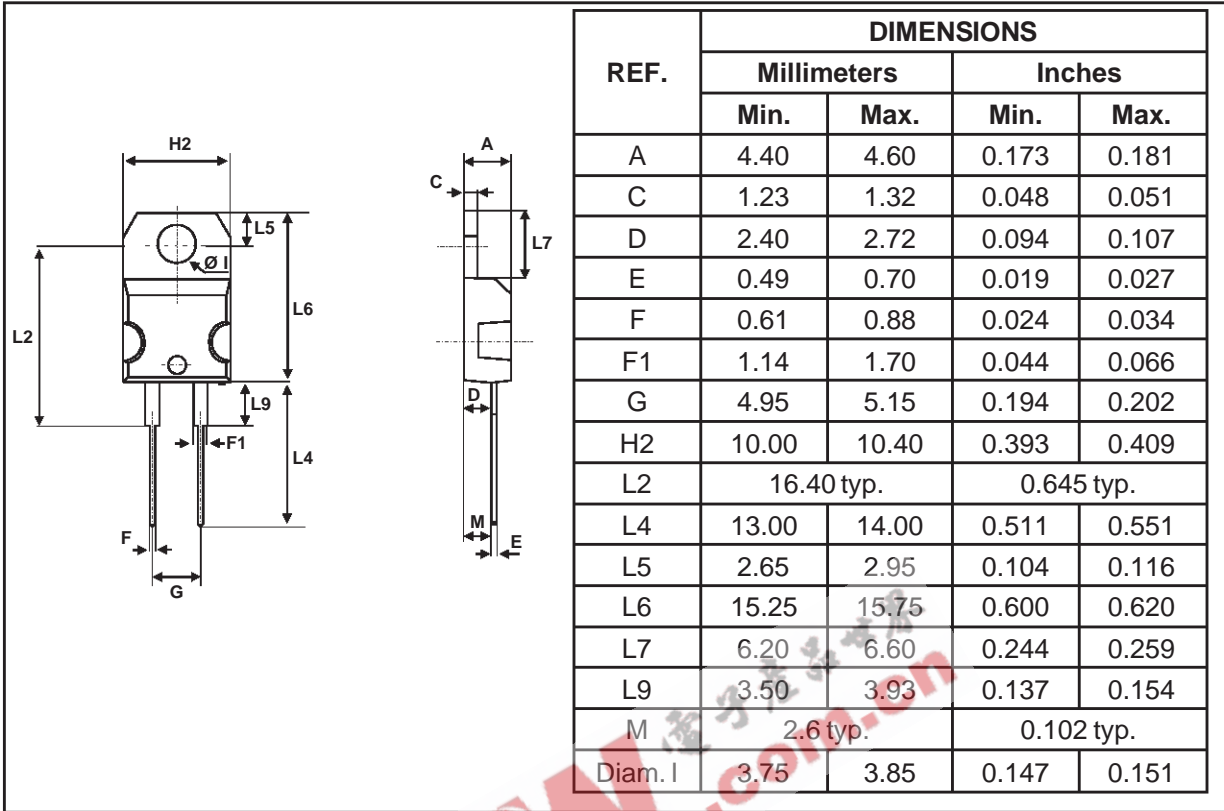


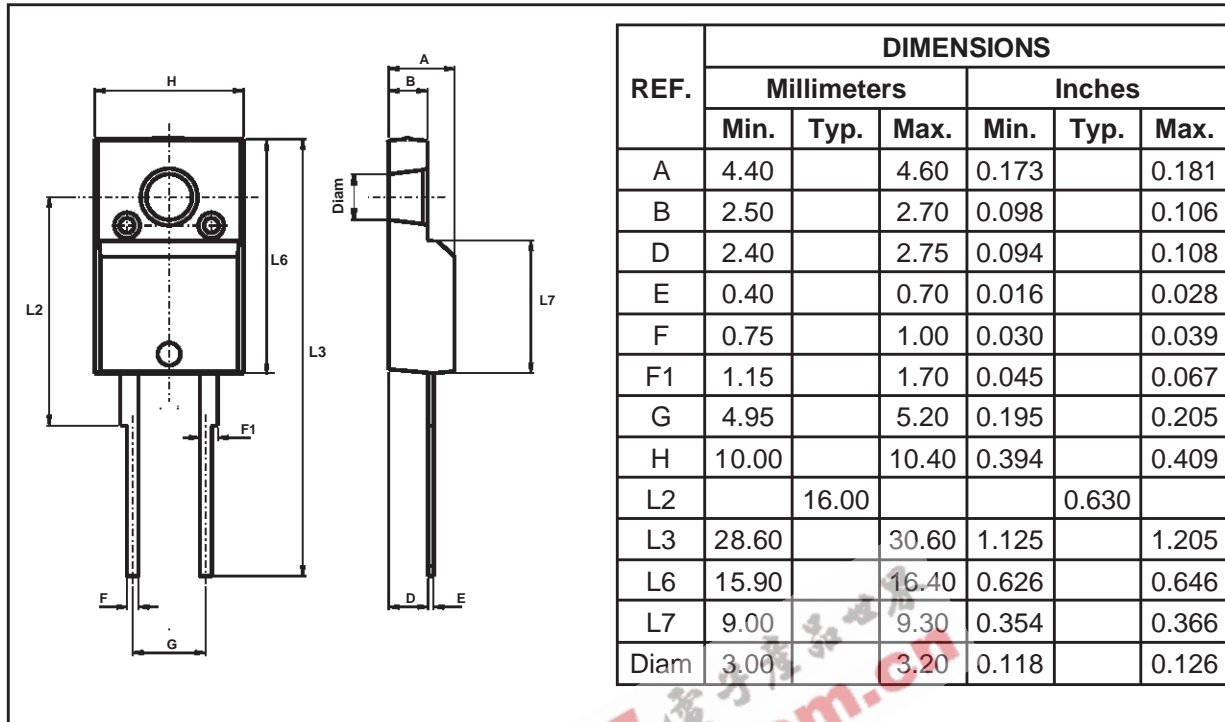
FOOTPRINT DIMENSIONS (in millimeters)



STPS745D/F/G

PACKAGE MECHANICAL DATA
TO-220AC



PACKAGE MECHANICAL DATA
 ISOWATT220AC


Type	Marking	Package	Weight	Base qty	Delivery mode
STPS745D	STPS745D	TO-220AC	1.86 g.	50	Tube
STPS745F	STPS745F	ISOWATT220AC	2 g.	50	Tube
STPS745G	STPS745G	D ² PAK	1.48 g.	50	Tube
STPS745G-TR	STPS745G	D ² PAK	1.48 g.	1000	Tape & reel

- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N.m
- Maximum torque value: 0.7 N.m.
- Epoxy meets UL94,V0

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